# Circular Beam Low Operating Current

# **HITACHI**

ADE-208-1419C (Z)

Rev.3 Mar. 2002

#### **Description**

The HL6335/36G are  $0.63~\mu m$  band AlGaInP laser diodes can be operated with low operating current. These products were designed by self aligned refractive index (SRI) active layer structure. These are suitable as a light source for laser levelers, laser scanners and optical equipment for measurement.

#### **Application**

- Laser leveler
- Laser scanner
- Measurement

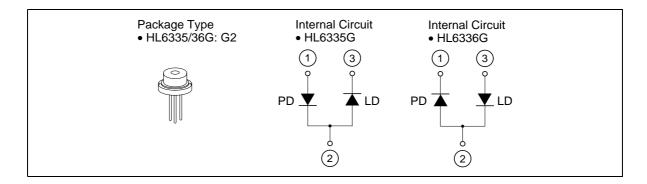
#### **Features**

Optical output power : 5 mW CW
 Visible light output : 635 nm Typ
 Low operating current : 25 mA Typ

• Low aspect ratio : 1.2 Typ (almost circular beam)

• Operating temperature : +50°C

• TM mode oscillation





#### **Absolute Maximum Ratings**

 $(T_c = 25^{\circ}C)$ 

Item	Symbol	Value	Unit	
Optical output power	P <sub>o</sub>	5	mW	
Pulse optical output power	P <sub>O(Pulse)</sub>	6 *	mW	
LD reverse voltage	$V_{R(LD)}$	2	V	
PD reverse voltage	$V_{R(PD)}$	30	V	
Operating temperature	Topr	-10 to +50	°C	
Storage temperature	Tstg	-40 to +85	°C	

Note: Pulse condition : Pulse width  $\leq 1 \mu s$ , duty = 50%

## **Optical and Electrical Characteristics**

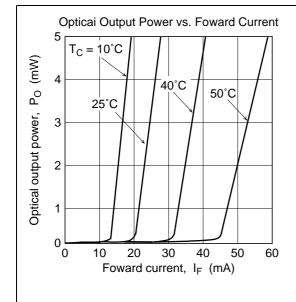
 $(T_c = 25^{\circ}C)$ 

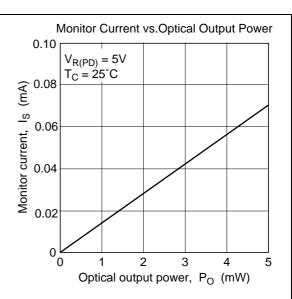
Item	Symbol	Min	Тур	Max	Unit	Test Condition
Optical output power	P <sub>o</sub>	5	_	_	mW	Kink free
Threshold current	lth	_	20	30	mA	
Slope efficiency	ηѕ	0.5	0.8	1.1	mW/mA	3 (mW) / (I <sub>(4mW)</sub> – I <sub>(1mW)</sub> )
Operating current	I <sub>OP</sub>	_	25	40	mA	$P_o = 5 \text{ mW}$
Operating voltage	V <sub>OP</sub>	_	2.4	2.7	V	$P_o = 5 \text{ mW}$
Lasing wavelength	λρ	630	635	640	nm	$P_o = 5 \text{ mW}$
Beam divergence parallel to the junction	θ//	13	17	25	deg.	$P_o = 5 \text{ mW}$
Beam divergence parpendicular to the junction	θ⊥	16	20	25	deg.	$P_o = 5 \text{ mW}$
Aspect ratio	θ⊥/θ//	_	1.2	1.5	_	$P_o = 5 \text{ mW}$
Monitor current	l <sub>s</sub>	0.03	0.07	0.12	mA	$P_{o} = 5 \text{ mW}, V_{R(PD)} = 5 \text{ V}$

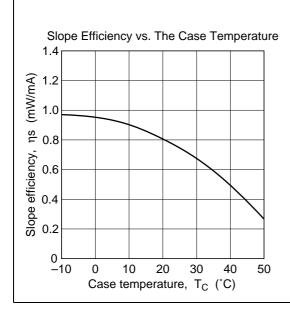
Notes: 1. Care must be taken in laser diodes handling to prevent optical damage caused by forward surges as well as by ESD.

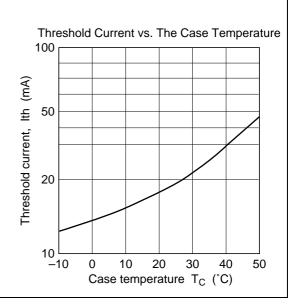
- 2. The wavefront performance is not guaranteed.
- 3. The beam has 12 deg offset against the package reference plane. Please take account it mounted on a board.

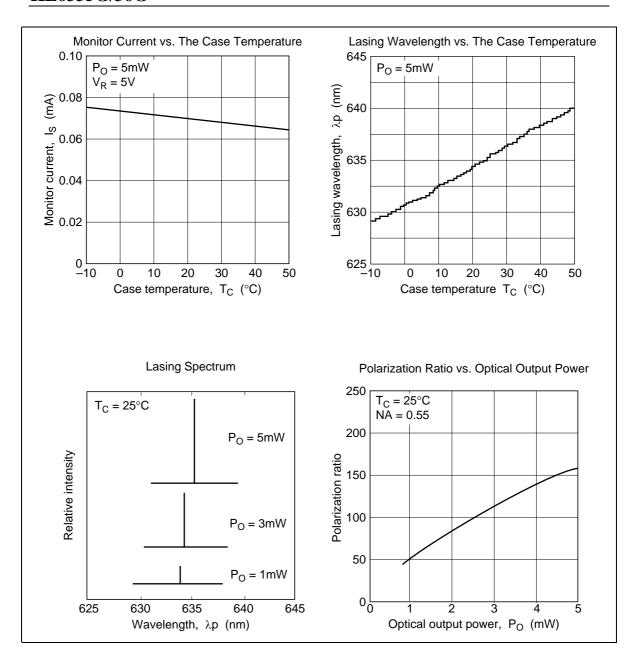
## **Typical Characteristic Curves**

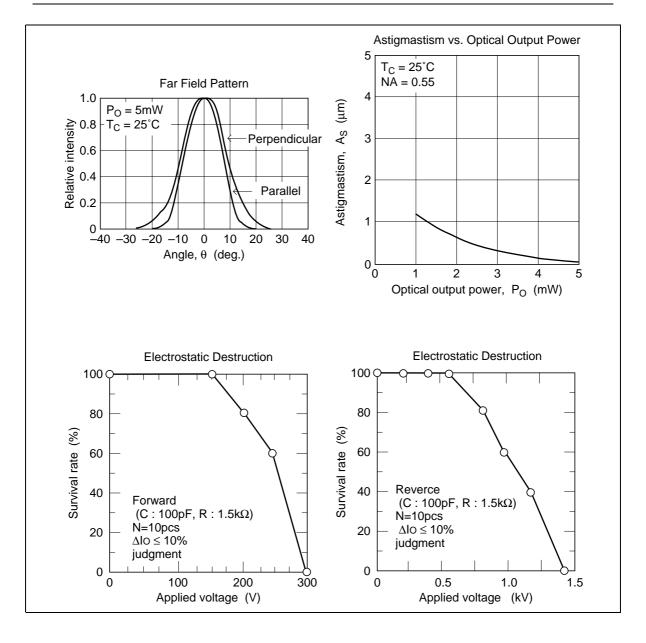




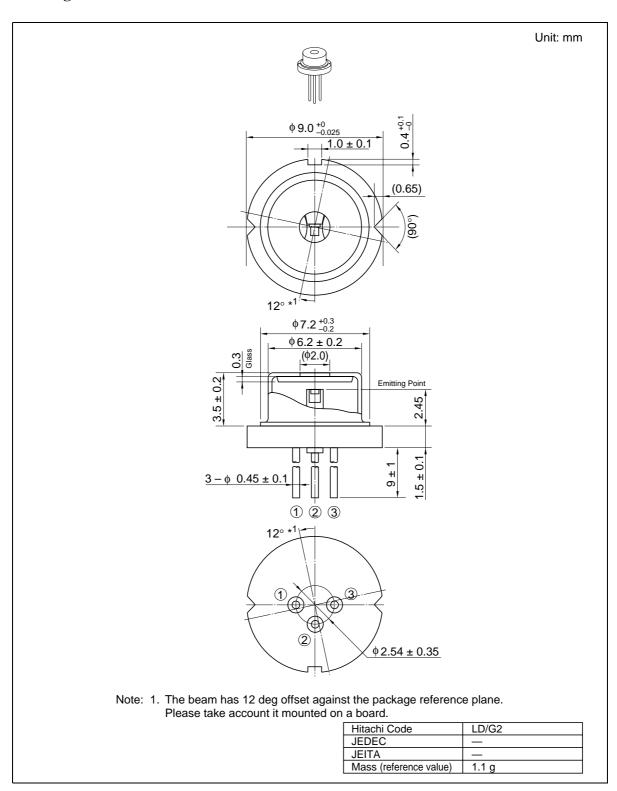






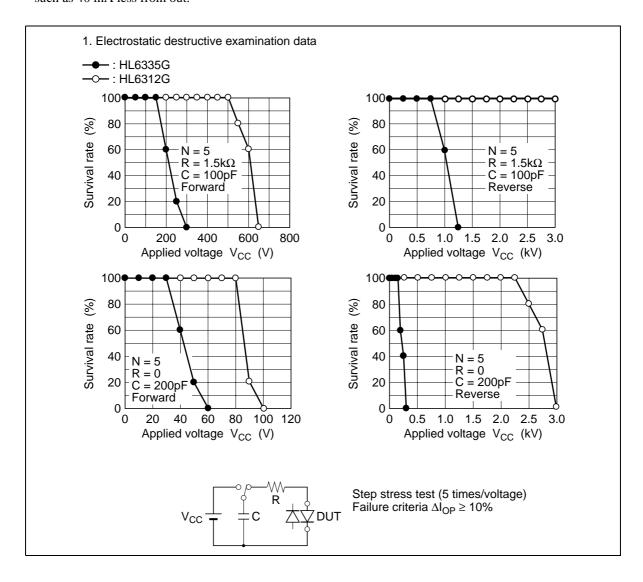


#### **Package Dimensions**

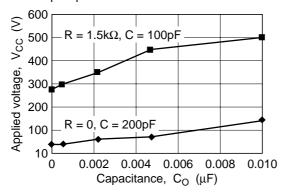


#### The Cautions on the Handing of HL6335G/36G

As laser diode differ from silicon devices, the area of safe operation (ASO) of laser diodes is not decided by power consumption alone, but optical output must be considered from view point of optical damage. These products are more sensitive to static electricity or an surge current than the conventional product. The following is test data of ESD (electric static damage). The operating condition should be within 5 mW and the working please should be keep small static electricity level such as 20 V less and small surge current such as 40 mA less from out.



### 2. Clamp Capacitance vs. ESD of HL6335G/36G



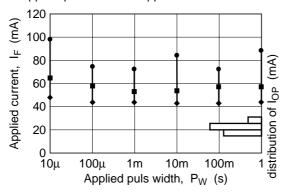
$$V_{CC} = C = DUT$$

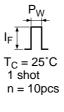
$$R_{O} = 2.2k\Omega$$

$$C_{O}$$

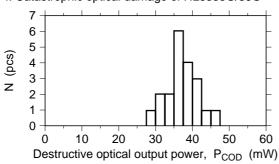
Step stress tast (5 times/voltage) Failure criteria  $\Delta I_{OP} \ge 10\%$ 

#### 3. Applied puls width vs. Applied current





#### 4. Catastrophic optical damage of HL6335G/36G



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- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.

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